



DMP4015SK3Q

P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(on) max}	l _D Τ _C = +25°C	
-40V	$11m\Omega$ @ $V_{GS} = -10V$	-35A	
-40 V	$15m\Omega$ @ $V_{GS} = -4.5V$	-30A	

Description

This new generation MOSFET has been designed to minimize the onstate resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- DC-DC Converters
- Power management functions
- Backlighting

Features and Benefits

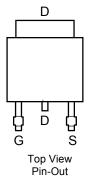
- 100% Unclamped Inductive Switch (UIS) test in production
- · Low on-resistance
- · Fast switching speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Available

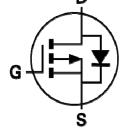
Mechanical Data

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Finish annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208³
- Weight: 0.33 grams (approximate)



Top View





Equivalent Circuit

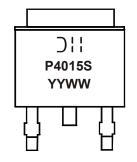
Ordering Information (Note 4 & 5)

Part Number	Compliance	Case	Packaging
DMP4015SK3Q-13	Automotive	TO252	2,500/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



O!! = Manufacturer's Marking
P4015S = Product Type Marking Code
YYWW = Date Code Marking
YY = Year (ex: 13 = 2013)
WW = Week (01 - 53)



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V_{DSS}	-40	V		
Gate-Source Voltage	V_{GSS}	±25	V		
Continuous Drain Current (Note 6) V _{GS} = -10V	Steady State	$T_{C} = +25^{\circ}C$ $T_{C} = +70^{\circ}C$	I _D	-35 -27	А
Continuous Drain Current (Note 6) V - 40V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-14 -11	Α
Continuous Drain Current (Note 6) V _{GS} = -10V	t<10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-22 -18	Α
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I _{DM}	-100	Α		
Maximum Body Diode Forward Current (Note 6)			I _S	-5.5	Α
Avalanche Current (Note 7)			I _{AS}	-57	Α
Avalanche Energy (Note 7)	E _{AS}	162	mJ		

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Total Power Dissipation (Note 6)	T _A = +25°C	C	3.5	W
Total Power Dissipation (Note 6)	T _A = +70°C	P_{D}	2.2	
Thermal Resistance, Junction to Ambient (Note 6)	Steady state	D	36	
Thermal Resistance, Junction to Ambient (Note o)	t<10s	$R_{\theta JA}$	15	°C/W
Thermal Resistance, Junction to Case (Note 6)	Steady state	R ₀ JC	4.5	
Operating and Storage Temperature Range		$T_{J_{I}}T_{STG}$	-55 to +150	°C

Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Cumbal	Min	Tyn	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	Symbol	IVIIII	Тур	IVIAX	Ullit	rest Condition	
, ,	D) (-40			V	\\ - 0\\ 1 - 250\\	
Drain-Source Breakdown Voltage	BV _{DSS}				-	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}			-1	μΑ	$V_{DS} = -40V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}			±100	nA	$V_{GS} = \pm 25V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(th)}	-1.5	-2	-2.5	V	$V_{DS} = V_{GS}$, $I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance		_	7	11	mΩ	$V_{GS} = -10V$, $I_D = -9.8A$	
Static Dialii-Source Oil-Resistance	R _{DS(ON)}	_	9	15	11122	$V_{GS} = -4.5V, I_D = -9.8A$	
Forward Transfer Admittance	Y _{fs}	_	26	_	S	$V_{DS} = -20V, I_{D} = -9.8A$	
Diode Forward Voltage	V_{SD}	_	-0.7	-1	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 9)					_		
Input Capacitance	C _{iss}	_	4234	_		V _{DS} = -20V, V _{GS} = 0V f = 1MHz	
Output Capacitance	Coss	_	1036	_	pF		
Reverse Transfer Capacitance	C _{rss}	_	526	_		1 - 1101112	
Gate Resistance	R _G	_	7.77	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Qg	_	47.5	_		V - 20V V - 5V	
Gate-Source Charge	Q _{gs}	_	14.2	_	nC	$V_{DS} = -20V, V_{GS} = -5V$ $I_{D} = -9.8A$	
Gate-Drain Charge	Q_{gd}	_	13.5	_			
Turn-On Delay Time	t _{D(on)}		13.2	_		$V_{GS} = -10V, V_{DD} = -20V,$ $R_{G} = 6\Omega, I_{D} = -1A$	
Turn-On Rise Time	t _r	_	10	_			
Turn-Off Delay Time	t _{D(off)}	_	302.7	_	ns		
Turn-Off Fall Time	t _f	_	137.9	_			

Notes:

- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate. 7. UIS in production with L = 0.1mH, $T_J = +25$ °C. 8 .Short duration pulse test used to minimize self-heating effect.

- 9. Guaranteed by design. Not subject to production testing.



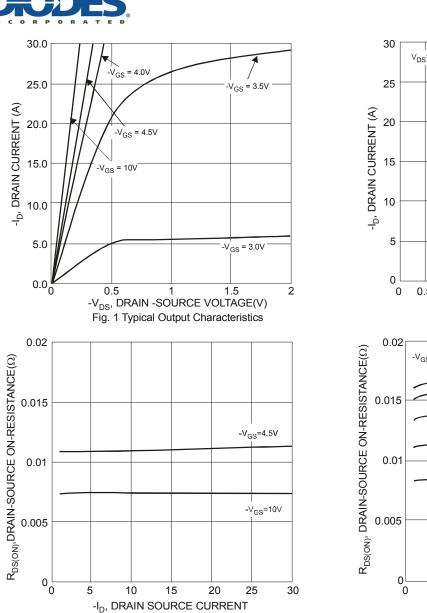


Fig. 3 Typical On-Resistance vs. Drain Current and Gate Voltage

> -V_{GS}=4.5V -I_D=5.0A

75

100

125

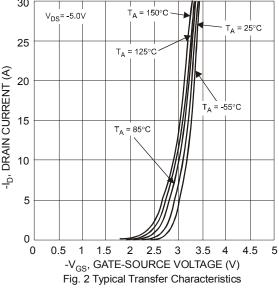
50

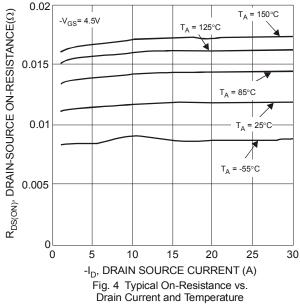
T_{.1}, JUNCTION TEMPERATURE (°C)

Fig. 5 On-Resistance Variation with Temperature

25

-V_{GS}=10V -I_D=10A





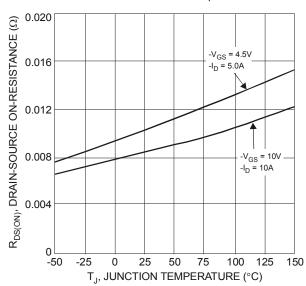


Fig. 6 On-Resistance Variation with Temperature

-25

1.6

1.4

1.2

8.0

0.6

-50

R_{DS(ON)}, DRAIN-SOURCE ON-RESISTANCE

(Normalized)



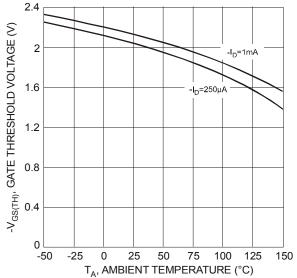
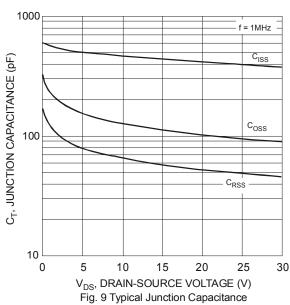
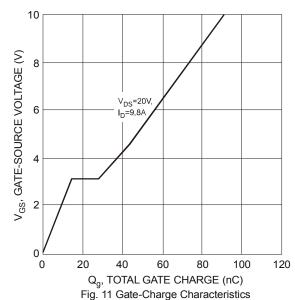


Fig. 7 Gate Threshold Variation vs. Ambient Temperature





30 25 T_A= 25°C -I_S, SOURCE CURRENT (A) 20 15 10 5 0 0.6 0 0.2 0.4 8.0 1.2 1.4 -V_{SD}, SOURCE-DRAIN VOLTAGE (V) Fig. 8 Diode Forward Voltage vs. Current

10000 1000 -I_{DSS}, LEAKAGE CURRENT (nA) T_A =125°C = T_A =85°C 100 10 T_A =25°C 0.1 5 10 15 20 25 30 $-V_{DS}$, DRAIN-SOURCE VOLTAGE(V)

Fig. 10 Typical Drain-Source Leakage Current vs. Voltage

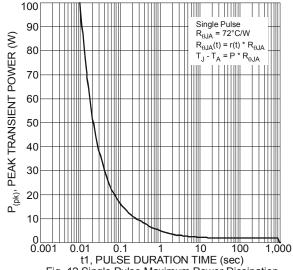
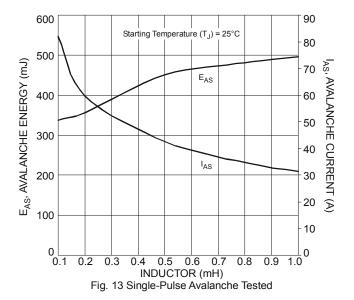
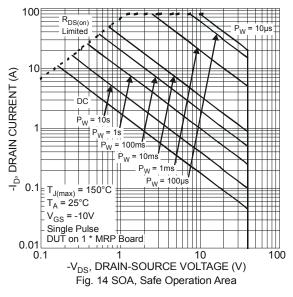


Fig. 12 Single Pulse Maximum Power Dissipation







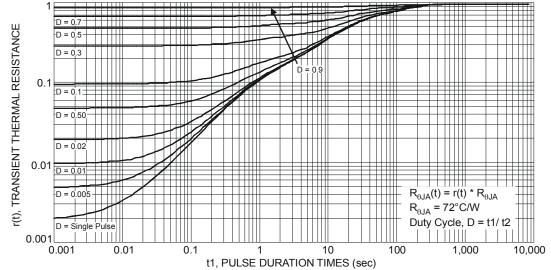
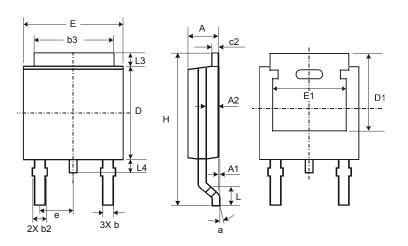


Fig. 15 Transient Thermal Resistance



Package Outline Dimensions

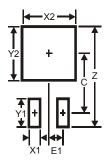
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



TO252					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A 1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
c2	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	_	-		
е	_	_	2.286		
Е	6.45	6.70	6.58		
E1	4.32	_	_		
Н	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	_		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
Z	11.6		
X1	1.5		
X2	7.0		
Y1	2.5		
Y2	7.0		
С	6.9		
E1	23		



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